



High Speed CMOS Logic – 54HC164

8-Bit Serial-Input / Parallel-Output Shift Register in bare die form

Rev 1.0
24/11/17

Description

The 54HC164 is fabricated using a 2.5µm 5V CMOS process and has the same high speed performance of LSTTL combined with CMOS low power consumption. The device consists of x2 serial data inputs, A and B, provided so that one input can be used as a data enable. Data is entered on each rising edge of the clock. A LOW on the master reset input (\overline{CLR}) clears the register, forcing all outputs LOW, independent of other inputs. Inputs are compatible with standard CMOS outputs and LSTTL via use of pull-up resistors. All inputs are equipped with protection circuits against static discharge & transient excess voltage.

Features:

- Output Drive Capability: 10 LSTTL Loads
- Low Input Current: 1µA
- Outputs directly interface CMOS, NMOS and TTL
- Operating Voltage Range: 2V to 6V
- CMOS High Noise Immunity
- Function compatible with 54LS164
- Full Military Temperature Range.

Ordering Information

The following part suffixes apply:

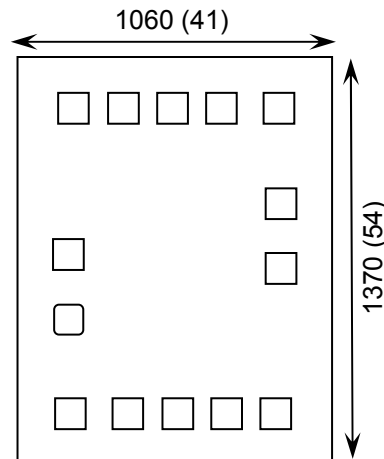
- No suffix - MIL-STD-883 /2010B Visual Inspection
- “H” - MIL-STD-883 /2010B Visual Inspection
+ MIL-PRF-38534 Class H LAT
- “K” - MIL-STD-883 /2010A Visual Inspection (Space)
+ MIL-PRF-38534 Class K LAT

LAT = Lot Acceptance Test.

For further information on LAT process flows see below.

www.siliconsupplies.com/quality/bare-die-lot-qualification

Die Dimensions in µm (mils)



Supply Formats:

- Default – Die in Waffle Pack (400 per tray capacity)
- Sawn Wafer on Tape – On request
- Unsawn Wafer – On request
- Die Thickness <=> 350µm(14 Mils) – On request
- Assembled into Ceramic Package – On request

Mechanical Specification

Die Size (Unsawn)	1060 x 1370 41 x 54	µm mils
Minimum Bond Pad Size	100 x 100 3.94 x 3.94	µm mils
Die Thickness	350 (±20) 13.78 (±0.79)	µm mils
Top Metal Composition	Al 1%Si 1.1µm	
Back Metal Composition	N/A – Bare Si	

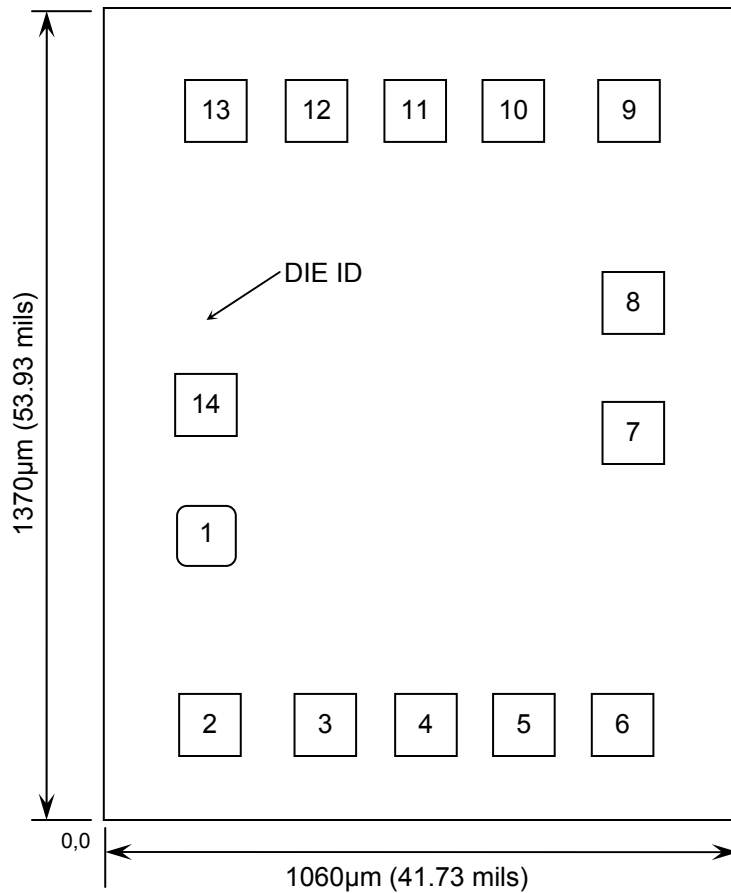




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Pad Layout and Functions



PAD	FUNCTION	COORDINATES (mm)	
		X	Y
1	A	0.117	0.439
2	B	0.124	0.115
3	Q _A	0.3195	0.115
4	Q _B	0.4875	0.115
5	Q _C	0.6555	0.115
6	Q _D	0.8235	0.115
7	GND	0.841	0.61
8	CLK	0.841	0.831
9	$\overline{\text{CLR}}$	0.833	1.155
10	Q _E	0.6385	1.155
11	Q _F	0.4705	1.155
12	Q _G	0.3025	1.155
13	Q _H	0.1345	1.155
14	V _{CC}	0.117	0.662

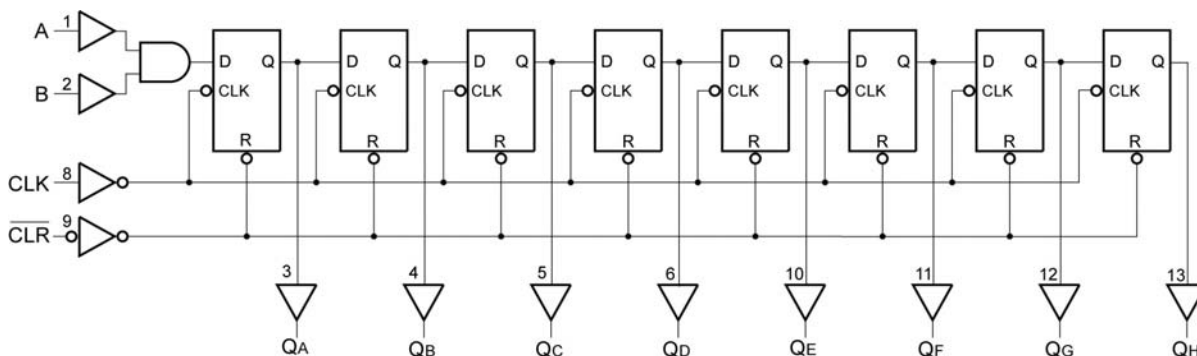
CONNECT CHIP BACK TO V_{CC} OR FLOAT

Function Table

INPUTS				OUTPUTS		
$\overline{\text{CLR}}$	CLK	A	B	Q _A	Q _B	... Q _H
L	X	X	X	L	L	L
H	L	X	X	Q _{A0}	Q _{B0}	Q _{H0}
H	↑	H	H	H	Q _{AN}	Q _{GN}
H	↑	L	X	L	Q _{AN}	Q _{GN}
H	↑	X	L	L	Q _{AN}	Q _{GN}

Logic Diagram

D = Data Input
Q_{An} - Q_{Gn} = Data shift from preceding register on rising edge clock input





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Absolute Maximum Ratings¹

PARAMETER	SYMBOL	VALUE	UNIT
DC Supply Voltage (Referenced to GND)	V_{CC}	-0.5 to +7.0	V
DC Input Voltage (Referenced to GND)	V_{IN}	-0.5 to $V_{CC} + 0.5$	V
DC Output Voltage (Referenced to GND)	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
DC Input Current, per pin	I_{IN}	±20	mA
DC Output Current, per pin	I_{OUT}	±25	mA
DC V_{CC} or GND Current, per pin	I_{CC}	±50	mA
Power Dissipation in Still Air	P_D	750	mW
Storage Temperature Range	T_{STG}	-65 to 150	°C

1. Operation above the absolute maximum rating may cause device failure. Operation at the absolute maximum ratings, for extended periods, may reduce device reliability. 2. Measured in plastic DIP package, results in die form are dependent on die attach and assembly method.

Recommended Operating Conditions³ (Voltages referenced to GND)

PARAMETER	SYMBOL	MIN	MAX	UNITS
DC Supply Voltage	V_{CC}	2	6	V
DC Input or Output Voltage	V_{IN}, V_{OUT}	0	V_{CC}	V
Operating Temperature Range	T_J	-55	+125	°C
Input Rise and Fall Time	$V_{CC} = 2.0V$	0	1000	Ns
	$V_{CC} = 4.5V$	0	500	
	$V_{CC} = 6.0V$	0	400	

3. This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{IN} and V_{OUT} should be constrained to the range $GND \leq (V_{IN} \text{ or } V_{OUT}) \leq V_{CC}$. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

DC Electrical Characteristics (Voltages referenced to GND)

PARAMETER	SYMBOL	V_{CC}	CONDITIONS	LIMITS			UNITS
				25°C	85°C	FULL RANGE ⁴	
Minimum High-Level Input Voltage	V_{IH}	2V	$V_{OUT} = 0.1V \text{ or } V_{CC} - 0.1V$ $ I_{OUT} \leq 20\mu A$	1.5	1.5	1.5	V
		3V		2.1	2.1	2.1	
		4.5V		3.15	3.15	3.15	
		6.0V		4.2	4.2	4.2	
Maximum Low-Level Input Voltage	V_{IL}	2V	$V_{OUT} = 0.1V \text{ or } V_{CC} - 0.1V$ $ I_{OUT} \leq 20\mu A$	0.5	0.5	0.5	V
		3V		0.9	0.9	0.9	
		4.5V		1.35	1.35	1.35	
		6.0V		1.8	1.8	1.8	

4. $-55^\circ C \leq T_J \leq +125^\circ C$





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DC Electrical Characteristics (Voltages Referenced to GND)

PARAMETER	SYMBOL	V _{CC}	CONDITIONS	LIMITS			UNITS
				25°C	85°C	FULL RANGE ⁴	
Minimum High-Level Output Voltage	V _{OH}	2.0V	V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤ 20μA	1.9	1.9	1.9	V
		4.5V		4.4	4.4	4.4	
		6.0V		5.9	5.9	5.9	
		3.0V	V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤ 2.4mA	2.48	2.34	2.20	V
		4.5V		3.98	3.84	3.70	V
		6.0V		5.48	5.34	5.20	
Maximum Low-Level Output Voltage	V _{OL}	2.0V	V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤ 20μA	0.1	0.1	0.1	V
		4.5V		0.1	0.1	0.1	
		6.0V		0.1	0.1	0.1	
		3.0V	V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤ 2.4mA	0.26	0.33	0.40	V
		4.5V		0.26	0.33	0.40	V
		6.0V		0.26	0.33	0.40	V
Maximum Input Leakage Current	I _{IN}	6.0V	V _{IN} = V _{CC} or GND	±0.1	±1.0	±1.0	μA
Maximum Quiescent Supply Current	I _{CC}	6.0V	V _{IN} = V _{CC} or GND, I _{OUT} = 0μA	4	40	160	μA

AC Electrical Characteristics⁵

PARAMETER	SYMBOL	V _{CC}	CONDITIONS	LIMITS			UNITS
				25°C	85°C	FULL RANGE ⁴	
Maximum Clock Frequency, (50% duty cycle)	f _{max}	2.0V	C _L = 50pF, t _r = t _f = 6ns	10	10	10	ns
		3.0V		20	20	20	
		4.5V		40	35	30	
		6.0V		50	45	40	
Maximum Propagation Delay, CLK to Q	t _{PLH} , t _{PHL}	2.0V	C _L = 50pF, t _r = t _f = 6ns	160	200	250	ns
		3.0V		100	150	200	
		4.5V		32	40	48	
		6.0V		27	34	42	

5. Not production tested in die form, characterized by chip design and tested in package.





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AC Electrical Characteristics⁵

PARAMETER	SYMBOL	V _{CC}	CONDITIONS	LIMITS			UNITS
				25°C	85°C	FULL RANGE ⁴	
Maximum Propagation Delay, CLR to Q	t _{PHL}	2.0V	C _L = 50pF, t _r = t _f = 6ns	175	220	265	ns
		3.0V		100	150	200	
		4.5V		35	44	53	
		6.0V		30	37	45	
Maximum Output Transition time, Any Output	t _{TLH} , t _{THL}	2.0V	C _L = 50pF, t _r = t _f = 6ns	75	95	110	ns
		3.0V		27	32	36	
		4.5V		15	19	22	
		6.0V		13	16	19	
Maximum Input Capacitance	C _{IN}	-	-	10	10	10	pF
Power Dissipation Capacitance Per Gate ⁶	C _{PD}	-	T _J = 25°C, V _{CC} = 5.0V	TYPICAL			pF
				180			

6. Used to determine the no-load dynamic power consumption: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

Timing Requirements⁵

PARAMETER	SYMBOL	V _{CC}	CONDITIONS	LIMITS			UNITS
				25°C	85°C	FULL RANGE ⁴	
Minimum Setup Time, A or B to Clock	t _{su}	2.0V	t _r = t _f = 6ns	25	35	40	ns
		3.0V		15	20	25	
		4.5V		7	8	9	
		6.0V		5	6	6	
Minimum Hold Time, Clock to A or B	t _h	2.0V	t _r = t _f = 6ns	3	3	3	ns
		3.0V		3	3	3	
		4.5V		3	3	3	
		6.0V		3	3	3	
Minimum Recovery Time, Reset Inactive to Clock	t _{rec}	2.0V	t _r = t _f = 6ns	3	3	3	ns
		3.0V		3	3	3	
		4.5V		3	3	3	
		6.0V		3	3	3	
Minimum Pulse Width, Clock	t _w	2.0V	t _r = t _f = 6ns	50	60	75	ns
		3.0V		26	35	45	
		4.5V		12	15	20	
		6.0V		10	12	15	
Maximum Input Rise & Fall Times	t _r , t _f	2.0V	t _r = t _f = 6ns	1000	1000	1000	ns
		3.0V		800	800	800	
		4.5V		500	500	500	
		6.0V		400	400	400	





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Switching Waveforms

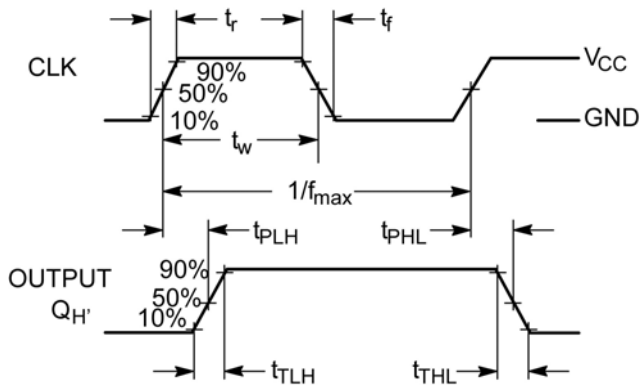


Figure 1 – Clock Propagation Delay & Output Timing

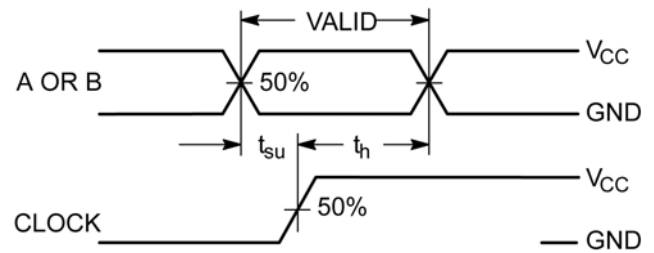


Figure 2 – Data Transition Timing, Serial Input & Clock

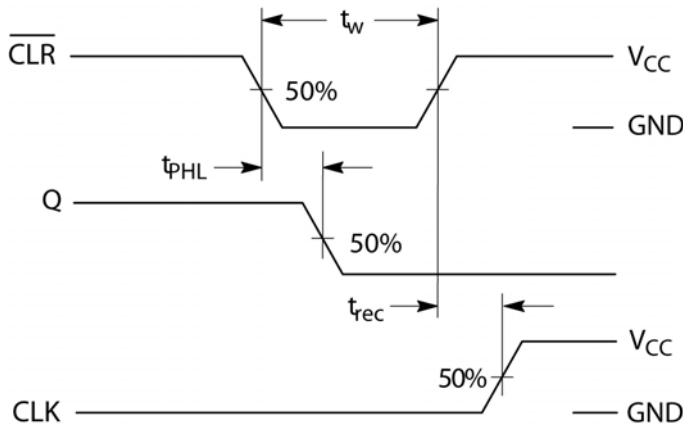
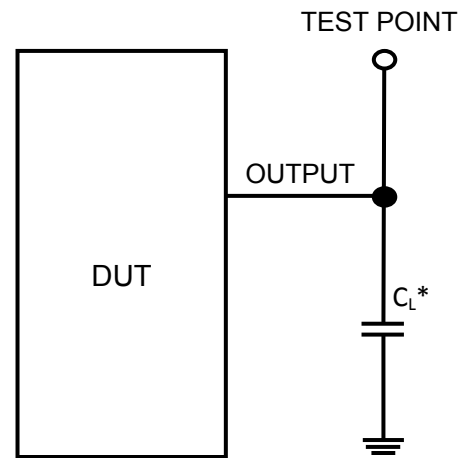


Figure 3 – Reset to Output Propagation Delay & Timing



* Includes all probe and jig capacitance

Figure 4 – Test Setup

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